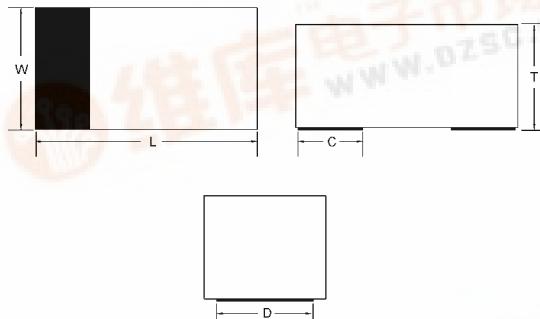


TSS70L

0.07Amp Surface Mount Schottky Barrier Diode

1005



Features

- ◆ Designed for mounting on small surface
- ◆ Extremely thin/leadless package
- ◆ Low capacitance
- ◆ Low forward voltage drop
- ◆ High temperature soldering:
260°C/10 seconds at terminals
- ◆ Chip version in 1005

Mechanical Data

- ◆ Case: 1005 Standard package, molded plastic
- ◆ Terminals: Gold plated, solderable per
MIL-STD-750, method 2026.
- ◆ Polarity: Indicated by cathode band
- ◆ Mounting position: Any
- ◆ Package code: RW
- ◆ Weight: 0.006 gram (approximately)

ITEM	1005
L	0.102(2.60) 0.095(2.40)
W	0.051(1.30) 0.043(1.10)
T	0.035(0.90) 0.027(0.70)
C	0.020(0.50) Typical
D	0.040(1.00) Typical

Dimensions in inches and (millimeters)

Maximum Ratings $T_A=25^{\circ}\text{C}$ unless otherwise specified

Type Number	Symbol	1005	Units
Repetitive Peak Reverse Voltage	V_{RRM}	70	V
Reverse Voltage	V_R	70	V
RMS Reverse Voltage	$V_{R(RMS)}$	49	V
Average Forward Current	I_O	70	mA
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I_{FSM}	100	mA
Power Dissipation	P_d	200	mW
Forward Voltage $IF=1\text{mA}$ $IF=15\text{mA}$	V_F	0.41 1.0	V
Reverse Leakage Current $VR=50\text{V}$	I_R	0.1	uA
Typical capacitance between terminals $VR=0\text{V}$, $f=1.0\text{MHz}$ reverse voltage	C_J	2	pF
Reverse Recovery Time ($IF=IR=10\text{mA}$, $Irr=0.1 \times IR$, $RL=100\Omega$)	T_{rr}	5	nS
Junction Temperature	T_J	-65 to + 125	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-65 to + 125	$^{\circ}\text{C}$

Version: A07

RATINGS AND CHARACTERISTIC CURVES(TSS70L)

Fig. 1 - Forward characteristics

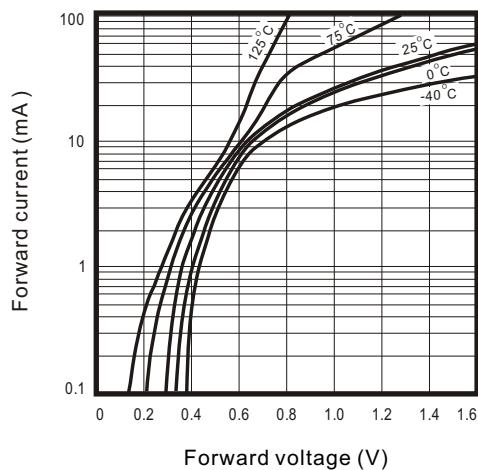


Fig. 2 - Reverse characteristics

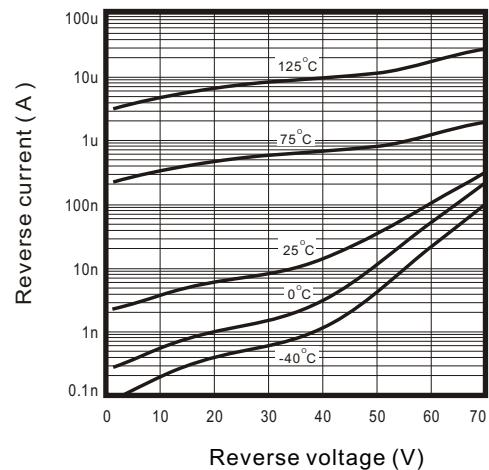


Fig.3 - Capacitance between terminals characteristics

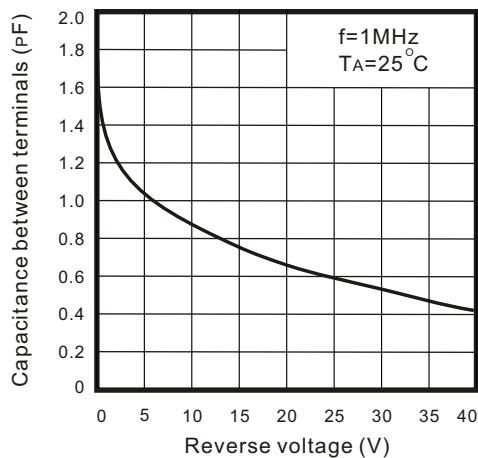


Fig.4 - Current derating curve

